

isc N-Channel MOSFET Transistor

IXTP80N12T2

• FEATURES

- Drain-Source On-Resistance: $R_{DS(on)}$ <17m Ω
- · With TO-220 packaging
- · High speed switching
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

- PFC stages
- LCD & PDP TV
- Power supply
- · Switching applications

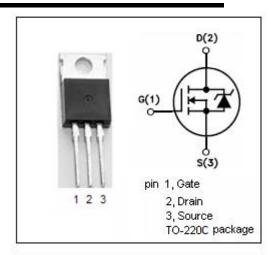


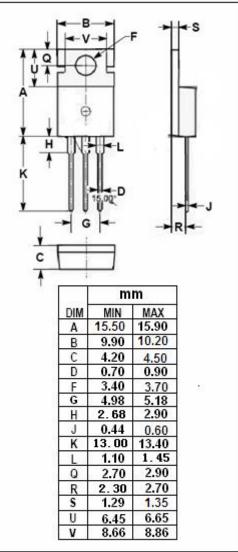
• ABSOLUTE MAXIMUM RATINGS(T_a=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	120	V	
V _{GSS}	Gate-Source Voltage ±20		V	
I _D	Drain Current-Continuous@Tc=25°C Tc=100°C	10.4 6.6	А	
I_{DM}	Drain Current-Single Pulsed	80	А	
P_D	Total Dissipation	325	W	
T _j	Operating Junction Temperature	-55~175	°C	
T _{stg}	Storage Temperature	-55~175	$^{\circ}$	

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT
Rth(ch-c)	Channel-to-case thermal resistance	0.46	°C/W
Rth(ch-a)	Rth(ch-a) Channel-to-ambient thermal resistance		°C/W







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 0.25mA	120			V
$V_{\text{GS(th)}}$	Gate Threshold Voltage	V _{DS} =V _{GS} ; I _D =0.1mA	2.5		4.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =40A			17	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V;V _{DS} = 0V			±0.1	μ A
Ipss	Drain-Source Leakage Current	V _{DS} = 120V; V _{GS} = 0V;Tj=25℃ V _{DS} = 120V; V _{GS} = 0V;Tj=175℃			5 175	μ А
V_{SDF}	Diode forward voltage	I _{SD} =40A, V _{GS} = 0 V			1.5	V

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